Product data sheet

1. General description

Dual common cathode power Schottky diode designed for high frequency switched mode power supplies in a TO-220 plastic package.

2. Features and benefits

- Trench structure
- · High junction temperature up to 150°C
- · High efficiency
- Low forward voltage drop, negligible switching losses

3. Applications

- · DC to DC converters
- Freewheeling diode
- · OR-ing diode

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{RRM}	repetitive peak reverse voltage		-	-	100	V
I _{F(AV)}	average forward current	δ = 0.5 ; T _{mb} ≤ 133 °C; square-wave pulse; per diode; Fig. 1; Fig. 2; Fig. 3	-	-	20	Α
$I_{O(AV)}$	average output current	δ = 0.5 ; T _{mb} ≤ 130 °C; square-wave pulse; both diodes conducting	-	-	40	Α
Static charac	cteristics					
V_{F}	forward voltage	I _F = 10 A; T _j = 25 °C; <u>Fig. 6</u> ; per diode	-	0.53	0.59	V
		I _F = 10 A; T _j = 125 °C; <u>Fig. 6</u> ; per diode	-	0.49	0.56	V
		I _F = 20 A; T _j = 25 °C; <u>Fig. 6</u> ; per diode	-	0.64	0.71	V
		I _F = 20 A; T _j = 125 °C; <u>Fig. 6</u> ; per diode	-	0.61	0.68	V
I _R	reverse current	V _R = 100 V; T _j = 25 °C; <u>Fig. 7</u> ; <u>Fig. 8</u> ; per diode	-	-	50	μΑ
		V _R = 100 V; T _j = 125 °C; <u>Fig. 7</u> ; <u>Fig. 8</u> ; per diode	-	-	30	mA

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5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	A1	anode 1		A1
2	K	cathode		
3	A2	anode 2		K sym125
mb	К	mounting base; connected to cathode	TO-220E	

6. Ordering information

Table 3. Ordering information

Type number	Package						
	Name	Description	Version				
WNS40H100C	TO-220E	plastic single-ended package; heatsink mounted; 1 mounting hole; 3-lead TO-220AB	TO-220E				

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{RRM}	repetitive peak reverse voltage		-	100	V
V_{RWM}	limiting crest working reverse voltage		-	100	V
V_R	limiting reverse voltage	DC	-	100	V
I _{F(AV)}	average forward current	δ = 0.5 ; T _{mb} ≤ 133 °C; square-wave pulse; per diode; Fig. 1; Fig. 2; Fig. 3	-	20	А
I _{O(AV)}	average output current	δ = 0.5 ; T _{mb} ≤ 130 °C; square-wave pulse; both diodes conducting	-	40	A
I _{FSM}	non-repetitive peak forward current	t_p = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; per diode; Fig. 4	-	380	А
		t_p = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; per diode	-	418	А
T _{stg}	storage temperature		-40	150	°C
Tj	junction temperature		-	150	°C

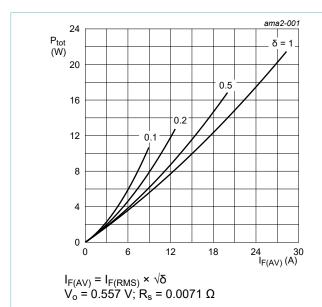


Fig. 1. Forward power dissipation as a function of average forward current; square waveform; maximum values; per diode

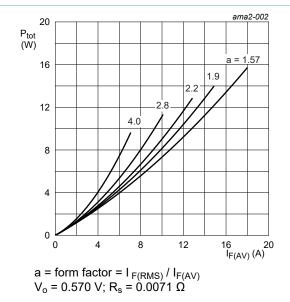


Fig. 2. Forward power dissipation as a function of average forward current; sinusoidal waveform; maximum values; per diode

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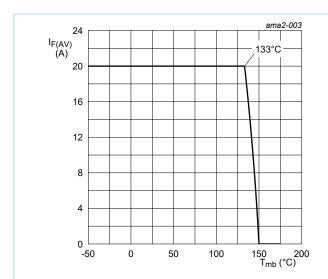


Fig. 3. Average forward current as a function of mounting base temperature; maximum values; per diode

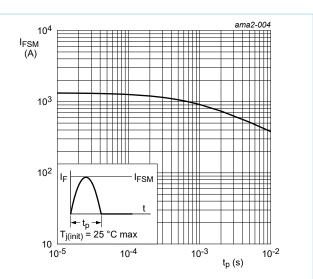


Fig. 4. Non-repetitive peak forward current as a function of pulse width; sinusoidal waveform; maximum values; per diode

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8. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance	per diode; Fig. 5	-	-	1	K/W
	from junction to mounting base	both diodes conducting	-	-	0.6	K/W
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	-	60	-	K/W

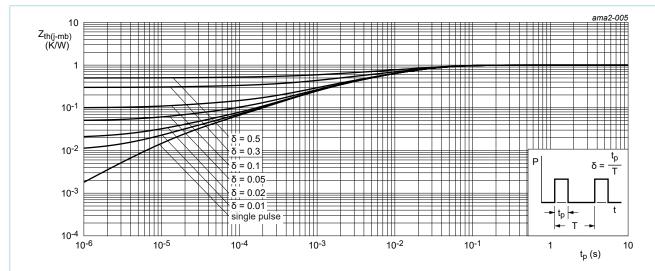


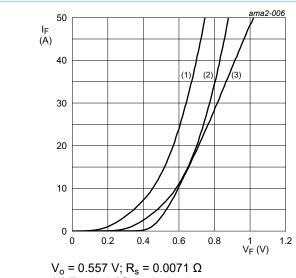
Fig. 5. Transient thermal impedance from junction to mounting base as a function of pulse duration; maximum values; per diode

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9. Characteristics

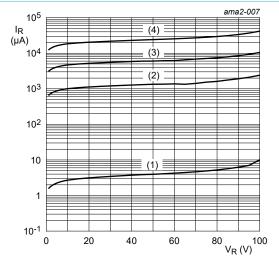
Table 6. Characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit	
Static characte	Static characteristics							
V _F	forward voltage	I _F = 10 A; T _j = 25 °C; <u>Fig. 6</u> ; per diode		-	0.53	0.59	V	
		I _F = 10 A; T _j = 125 °C; <u>Fig. 6</u> ; per diode		-	0.49	0.56	V	
		$I_F = 20 \text{ A}; T_j = 25 ^{\circ}\text{C}; Fig. 6; per diode}$ -	-	0.64	0.71	V		
		I _F = 20 A; T _j = 125 °C; <u>Fig. 6</u> ; per diode		-	0.61	0.68	V	
I _R	reverse current	V_R = 100 V; T_j = 25 °C; <u>Fig. 7</u> ; <u>Fig. 8</u> ; per diode		-	-	50	μΑ	
		V _R = 100 V; T _j = 125 °C; <u>Fig. 7</u> ; <u>Fig. 8</u> ; per diode		-	-	30	mA	



⁽¹⁾ T_i = 150 °C; typical values

Fig. 6. Forward current as a function of forward voltage; per diode



(1) T_j = 25 °C; typical values

Fig. 7. Reverse leakage current as a function of reverse voltage; per diode; typical values

⁽²⁾ T_i = 150 °C; maximum values

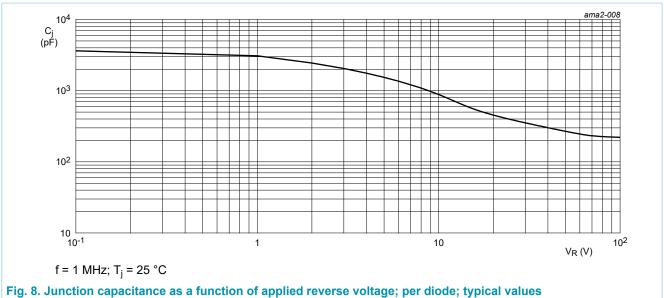
⁽³⁾ T_i = 25 °C; maximum values

⁽²⁾ $T_j = 100 \,^{\circ}\text{C}$; typical values (3) $T_j = 125 \,^{\circ}\text{C}$; typical values

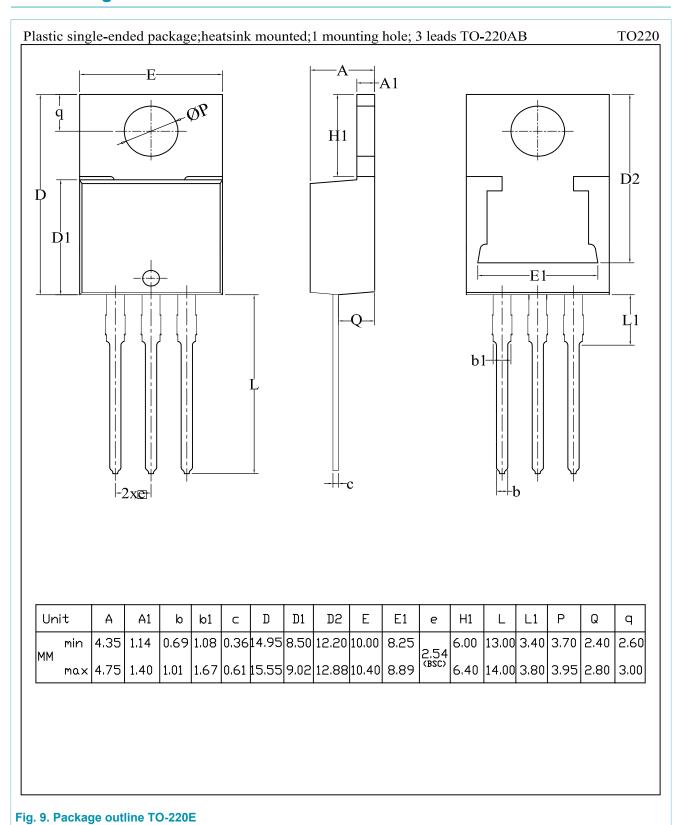
⁽⁴⁾ T_i = 150 °C; typical values

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10. Package outline



11. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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For more information, please visit: http://www.ween-semi.com
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